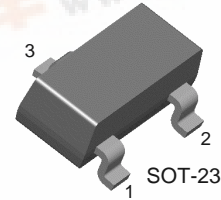


FAIRCHILD
SEMICONDUCTOR®

KST4403

Switching Transistor



1. Base 2. Emitter 3. Collector

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

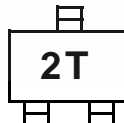
Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	-40	V
V_{CEO}	Collector-Emitter Voltage	-40	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current	-600	mA
P_C	Collector Power Dissipation	350	mW
T_{STG}	Storage Temperature	150	$^\circ\text{C}$

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C = -0.1\text{mA}, I_E = 0$	-40		V
BV_{CEO}	* Collector-Emitter Breakdown Voltage	$I_C = -1.0\text{mA}, I_B = 0$	-40		V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E = -0.1\text{mA}, I_C = 0$	-5		V
I_{BEV}	Base Cut-off Current	$V_{CE} = -35\text{V}, V_{BE} = -0.4\text{V}$		-0.1	μA
I_{CEX}	Collector Cut-off Current	$V_{CE} = -35\text{V}, V_{BE} = -0.4\text{V}$		-0.1	μA
h_{FE}	DC Current Gain	$V_{CE} = -1\text{V}, I_C = -0.1\text{mA}$ $V_{CE} = -1\text{V}, I_C = -1.0\text{mA}$ $V_{CE} = -1\text{V}, I_C = -10\text{mA}$ * $V_{CE} = -2\text{V}, I_C = -150\text{mA}$ * $V_{CE} = -2\text{V}, I_C = -500\text{mA}$	30 60 100 100 20	300	
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = -150\text{mA}, I_B = -15\text{mA}$ $I_C = -500\text{mA}, I_B = -50\text{mA}$		-0.4 -0.75	V
$V_{BE(sat)}$	* Base-Emitter Saturation Voltage	$I_C = -150\text{mA}, I_B = -15\text{mA}$ $I_C = -500\text{mA}, I_B = -50\text{mA}$	-0.75	-0.95 -1.3	V
f_T	Current Gain Bandwidth Product	$I_C = -20\text{mA}, V_{CE} = -10\text{V}$ $f = 100\text{MHz}$	200		MHz
C_{ob}	Output Capacitance	$V_{CB} = -10\text{V}, I_E = 0$ $f = 140\text{KHz}$		8.5	pF
t_{ON}	Turn On Time	$V_{CC} = -30\text{V}, V_{BE} = -2\text{V}$ $I_C = -150\text{mA}, I_{B1} = -15\text{mA}$		35	ns
t_{OFF}	Turn Off Time	$V_{CC} = -30\text{V}, I_C = -150\text{mA}$ $I_{B1} = I_{B2} = -15\text{mA}$		255	ns

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Marking



Typical Characteristics

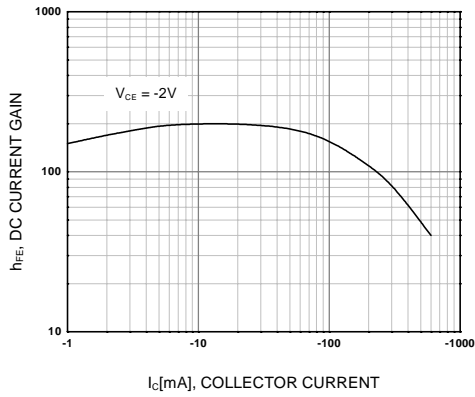


Figure 1. DC current Gain

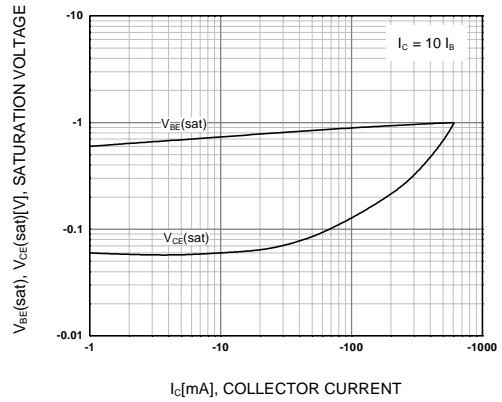


Figure 2. Base-Emitter Saturation Voltage
Collector-Emmitter Saturation Voltage

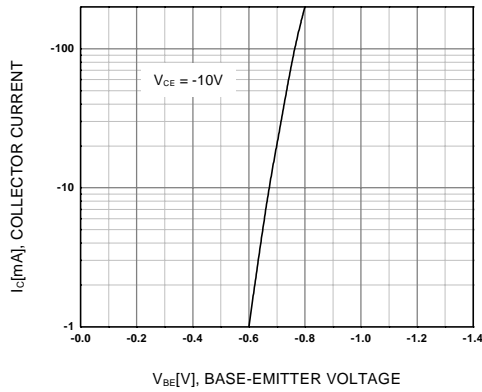


Figure 3. Base-Emitter On Voltage

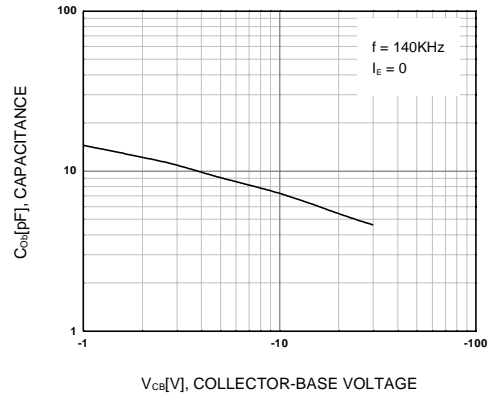


Figure 4. Collector-Base Capacitance

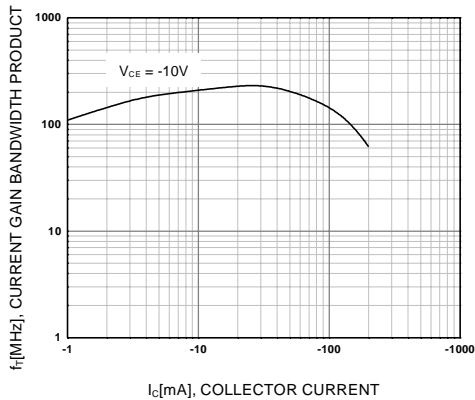
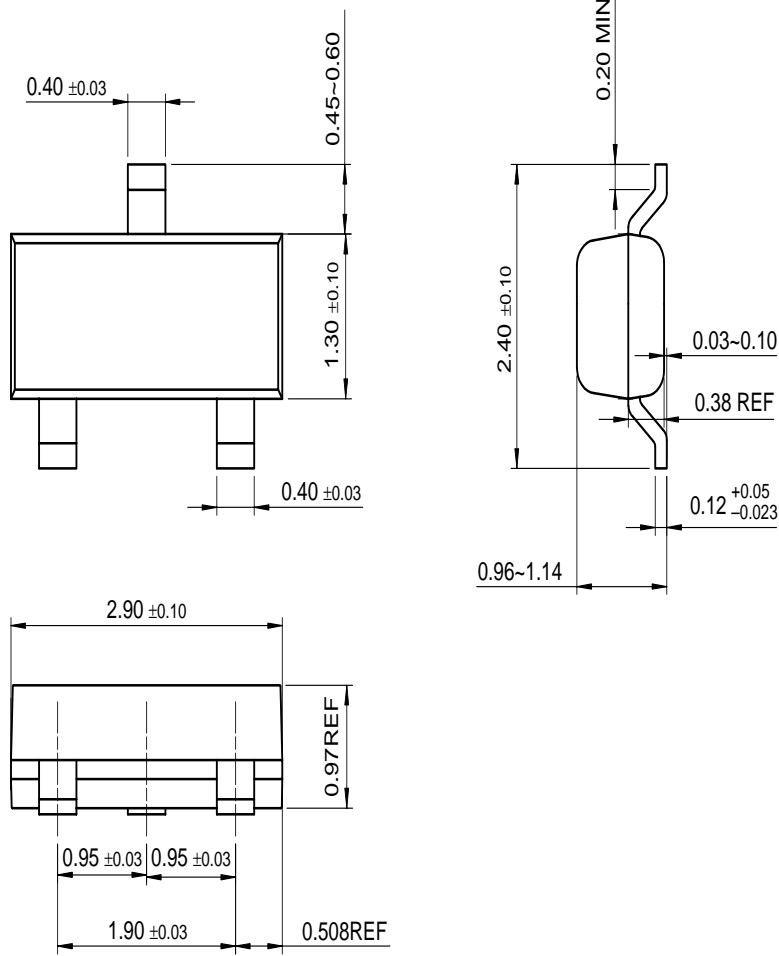


Figure 5. Current Gain Bandwidth Product

Package Dimensions

SOT-23



Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOMET™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I ² C™	OCX™	RapidConfigure™	UHC™
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The Power Franchise™		OPTOLOGIC®	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

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